Sample name	Narrow Well width (nm)		Wide Well width (nm)	Barrier width (nm)	Barrier semiconductor	Adjacent barriers semiconductor	Dopped type	$\left[\frac{1}{cm^3}\right]$
M4_3171	11.87		13.85	3.960	AlGaAs	$Al_{0.15}Ga_{0.85}As$		
$M4_{-}3172$	11.87	←	13.85	0.565	AlAs	$Al_{0.30}Ga_{0.70}As$		
$M4_{-}3226$	11.87	←	13.85	0.424	AlAs	$\mathrm{Al}_{0.30}\mathrm{Ga}_{0.70}\mathrm{As}$		
M4_3140	11.87	←	13.85	1.980	AlGaAs	$\mathrm{Al}_{0.15}\mathrm{Ga}_{0.85}\mathrm{As}$	n[Si]	6×10^{18}
$M4_{-}3141$	11.87		13.85	3.960	AlGaAs	$\mathrm{Al}_{0.15}\mathrm{Ga}_{0.85}\mathrm{As}$	n[Si]	6×10^{18}
M4_3521	11.87		23.74	1.980	AlGaAs	$Al_{0.15}Ga_{0.85}As$	n[Si]	6×10^{18}
$M4_{-}3522$	11.87		23.74	1.980	AlGaAs	$Al_{0.15}Ga_{0.85}As$	p[Be]	5×10^{16}
M4_3523	11.87	$z \rightarrow 0$	11.87	1.980	AlGaAs	$Al_{0.15}Ga_{0.85}As$	n[Si]	6×10^{18}